

isc N-Channel MOSFET Transistor

TK17E80W, ITK17E80W

• FEATURES

- Low drain-source on-resistance:
 $R_{DS(on)} \leq 0.29\Omega$.
- Enhancement mode:
 $V_{th} = 3.0$ to $4.0V$ ($V_{DS} = 10V$, $I_D = 0.85mA$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

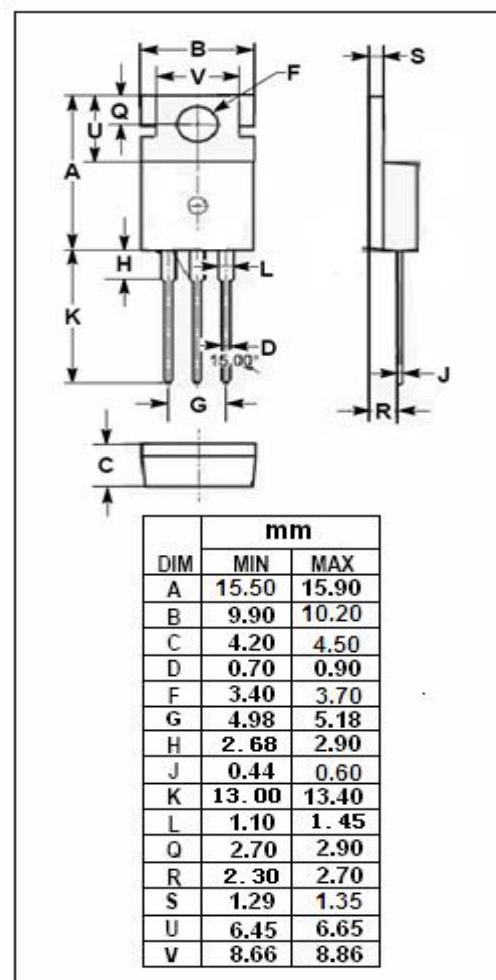
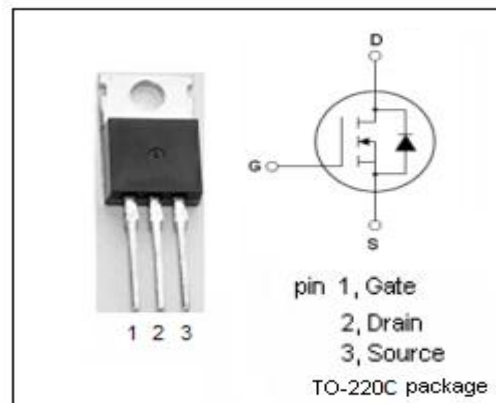
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	800	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	17	A
I_{DM}	Drain Current-Single Pulsed	68	A
P_D	Total Dissipation @ $T_c = 25^\circ C$	180	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.694	$^\circ C/W$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	83.3	$^\circ C/W$



isc N-Channel MOSFET Transistor**TK17E80W, ITK17E80W****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=10mA$	800			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=10V; I_D=0.85mA$	3.0		4.0	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=8.5A$			0.29	Ω
I_{GSS}	Gate-Source Leakage Current	$V_{GS} = \pm 20V; V_{DS} = 0V$			± 1	μA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=800V; V_{GS} = 0V$			10	μA
V_{SDF}	Diode forward voltage	$I_{DR} = 17A, V_{GS} = 0V$			1.7	V

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